

Switchmode Full Plastic Ultra-Fast Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- *Low T_{RR}
- *High Surge Capacity
- *Low Power Loss, High efficiency
- *175°C Operating Junction Temperature
- *Low Forward Voltage, High Frequency
- *High-Switching Speed Recovery Time
- *Plastic Material used Carries Underwriters Laboratory
- *Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	UFEF16C60C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	V _{R(RMS)}	420	V
Average Rectifier Forward Current (per diode) Total Device (Rated V _R), Tc=125℃	I _{F(AV)}	8 16	Α
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	16	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	150	А
Operating and Storage Junction Temperature Range	T_J,T_stg	-65 to +175	$^{\circ}\!\mathbb{C}$

THERMAL RESISTANCES

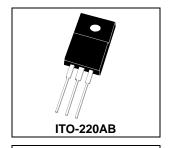
Typical Thermal Resistance junction to case	R _{θjc}	4.2	°C/w
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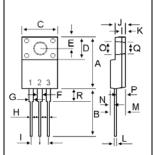
ELECTRICAL CHARACTERISTICS

LLLO INICAL CHARACTERIOTICS					
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 8 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 8 \text{ Amp } T_C = 125^{\circ}C$)	V _F		1.85 1.50	2.2	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.02 5	25 	uA
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A)	T _{rr}		22	25	ns

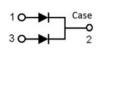
ULTRA FAST RECTIFIERS

16 AMPERES **600 VOLTS**

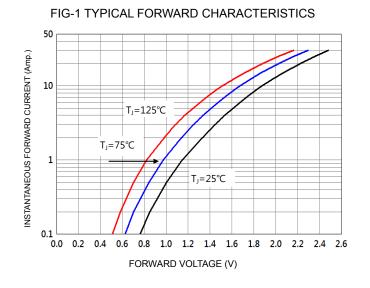




DIM	MILLIMETERS		
Dilvi	MIN	MAX	
Α	14.80	16.10	
В	12.65	13.80	
С	9.85	10.36	
D	4.60	6.80	
E	2.50	3.50	
F	1.00	1.45	
G	1.00	1.45	
Н	0.30	0.90	
- 1	2.40	2.70	
J	2.34	3.30	
K	0.55	1.30	
L	0.36	0.80	
M	4.20	4.90	
N	1.10	1.80	
0	2.90	3.50	
Р	2.50	3.15	
Q	2.90	3.50	
R	3.10	4.85	







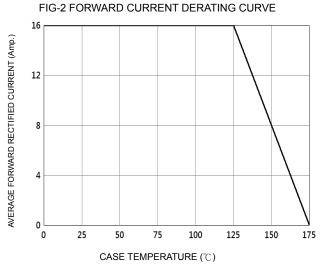
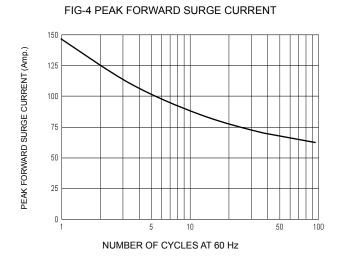
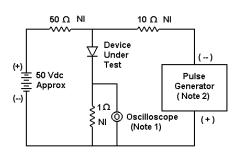
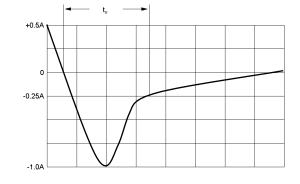


FIG-3 TYPICAL REVERSE CHARACTERISTICS $T_{j}=125^{\circ}C$ 0.01 $T_{j}=75^{\circ}C$ 0.001







Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

Set time base for 10/20 ns/cm FIG-5 Reverse Recovery Time Characteristic and Test Circuit Diagram



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